

77.76MHz, LVCMOS/LVTTL Oscillator Replacement

GENERAL DESCRIPTION



The ICS840-77 is a SONET Oscillator Replacement and a member of the HiPerClocks[™] family of high performance devices from ICS. The ICS840-77 uses a 19.44MHz crystal to synthesize 77.76MHz. The ICS840-77 has

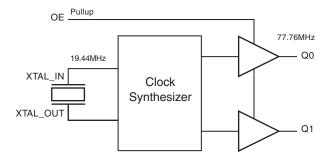
excellent jitter performance. The ICS840-77 is packaged in a small 8-pin TSSOP, making it ideal for use in systems with limited board space.

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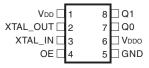
FEATURES

- One LVCMOS/LVTTL output, 15Ω output impedence
- Crystal oscillator interface designed for 19.44MHz, 18pF parallel resonant crystal
- Output frequency: 77.76MHz
- Random jitter: 2.82ps (typical)
- Deterministic jitter: 0.205ps (typical)
- 3.3V operating supply
- 0°C to 70°C ambient operating temperature
- Available in both standard and lead-free RoHS-compliant packages

BLOCK DIAGRAM



PIN ASSIGNMENT



ICS840-77

8-Lead TSSOP
4.40mm x 3.0mm x 0.925mm package body
G Package
Top View

ICS840-77

8-Lead SOIC
3.90mm x 4.92mm x 1.37mm body package

M Package

Top View

The Preliminary Information presented herein represents a product in prototyping or pre-production. The noted characteristics are based on initial product characterization. Integrated Circuit Systems, Incorporated (ICS) reserves the right to change any circuitry or specifications without notice.



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TABLE 1. PIN DESCRIPTIONS

Number	Name	Туре		Description
1	$V_{_{\mathrm{DD}}}$	Power		Power supply pin.
2, 3	XTAL_OUT, XTAL_IN	Input		Crystal oscillator interface. XTAL_IN is the input, XTAL_OUT is the output.
4	OE	Input Pullup		Output enable pin. When HIGH, outputs are enabled. When LOW, forces outputs to HiZ state. LVCMOS/LVTTL interface levels.
5	GND	Power		Power supply ground.
t4U.com	V _{DDO}	Power		Output supply pin.
7, 8	Q0, Q1	Output		Single-ended clock outputs. LVCMOS/LVTTL interface levels. 15Ω output impedence.

NOTE: Pullup refers to internal input resistors. See Table 2, Pin Characteristics, for typical values.

TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
R _{PULLUP}	Input Pullup Resistor			51		kΩ
R _{OUT}	Output Impedance			15		Ω

TABLE 3. CONTROL FUNCTION TABLE

Control Inputs	Output
OE	Q0, Q1
0	Hi-Z
1	Active



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ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V_{DD} 4.6V

Inputs, V_{I} -0.5V to V_{DD} + 0.5 V

Outputs, V_{O} -0.5V to V_{DDO} + 0.5V

Package Thermal Impedance, θ_{IA}

8 Lead TSSOP 101.7°C/W (0 mps) 8 Lead SOIC 112.7°C/W (0 lfpm)

Storage Temperature, T_{STG} -65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 4A. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 0.3V$, $T_A = 0$ °C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{DD}	Power Supply Voltage		3.0	3.3	3.6	٧
V _{DDO}	Output Supply Voltage		3.0	3.3	3.6	V
I _{DD}	Power Supply Current	$OE = V_{DD}$ (output enabled)		TBD		mA
I _{DDO}	Output Supply Current			TBD		

Table 4B. LVCMOS/LVTTL DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 0.3V$, $T_A = 0$ °C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{IH}	Input High Voltage		2		V _{DD} + 0.3	V
V _{IL}	Input Low Voltage		-0.3		0.8	V
I _{IH}	Input High Current	$V_{DD} = V_{IN} = 3.6V$			5	μΑ
I	Input Low Current	$V_{_{DD}} = 3.6V, \ V_{_{IN}} = 0V$	-150			μΑ
V _{OH}	Output High Voltage; NOTE 1		2.6			V
V _{OL}	Output Low Voltage; NOTE 1				0.5	V

NOTE 1: Outputs terminated with 50Ω to $V_{DDO}/2$. See Parameter Measurement Information Section,

TABLE 5. CRYSTAL CHARACTERISTICS

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		F	undamenta	I	
Frequency			19.44		MHz
Equivalent Series Resistance (ESR)			TBD		Ω
Shunt Capacitance				7	pF
Drive Level				TBD	μW

[&]quot;3.3V Output Load Test Circuit".



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Table 6. AC Characteristics, $V_{DD} = V_{DDO} = 3.3 V \pm 0.3 V$, $T_A = 0 ^{\circ} C$ to $70 ^{\circ} C$

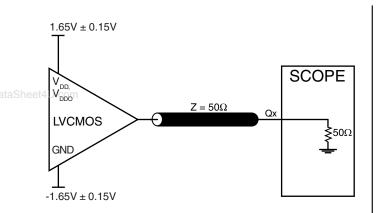
Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f _{out}	Output Frequency			77.76		MHz
t _{DJ}	Deterministic Jitter; NOTE 1			0.205		ps
t _{RJ}	Random Jitter; NOTE 1			2.82		ps
t _{RMS}	RMS of Total Distribution (σ); NOTE 1			2.85		ps
et4p-p.com	Peak-to-Peak Jitter; NOTE 1			2.18		ps
t _{acc}	Accumulated Jitter (σ); NOTE 1	n = 2 to 50000 cycles		4.0		ps
t _{osc}	Oscillation Start Up Time	Time at minimum operating voltage to be 0 s			10	ms
t_R/t_F	Output Rise/Fall Time	20% to 80%		650		ps
odc	Output Duty Cycle			50		%

NOTE 1: Measured using Wavecrest SIA-3000.



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PARAMETER MEASUREMENT INFORMATION

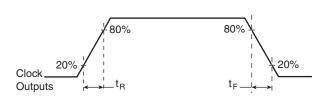


Q0, Q1
$$\frac{V_{DDO}}{2}$$

$$odc = \frac{t_{PW}}{t_{PERIOD}} \times 100\%$$

3.3V OUTPUT LOAD AC TEST CIRCUIT

OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD



OUTPUT RISE/FALL TIME



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APPLICATION INFORMATION

RECOMMENDATIONS FOR UNUSED INPUT AND OUTPUT PINS

NPUTS:

CRYSTAL INPUT:

For applications not requiring the use of the crystal oscillator input, both XTAL_IN and XTAL_OUT can be left floating. Though not required, but for additional protection, a $1k\Omega$ resistor can be tied from XTAL_IN to ground.

SELECT PINS:

All select pins have internal pull-ups and pull-downs; additional resistance is not required but can be added for additional protection. A $1k\Omega$ resistor can be used.

OUTPUTS:

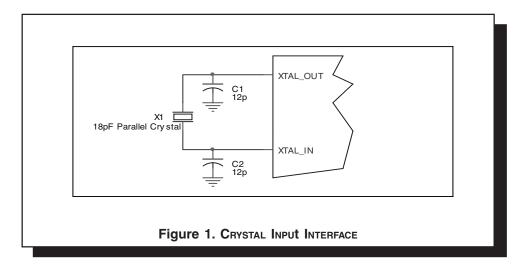
LVCMOS OUTPUT:

All unused LVCMOS output can be left floating. We recommend that there is no trace attached.

CRYSTAL INPUT INTERFACE

The ICS840-77 has been characterized with 18pF parallel resonant crystals. The capacitor values, C1 and C2, shown in *Figure 1* below were determined using a 19.44MHz, 18pF paral-

lel resonant crystal and were chosen to minimize the ppm error. The optimum C1 and C2 values can be slightly adjusted for different board layouts.





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RELIABILITY INFORMATION

Table 7A. θ_{JA} vs. Air Flow Table for 8 Lead TSSOP

 θ_{A} by Velocity (Meters per Second)

0

1

2.5

Multi-Layer PCB, JEDEC Standard Test Boards

101.7°C/W

90.5°C/W

89.8°C/W

Table 7B. $\boldsymbol{\theta}_{JA} vs.$ Air Flow Table 8 Lead SOIC

θ_{AA} by Velocity (Linear Feet per Minute)

0

200

500

Single-Layer PCB, JEDEC Standard Test Boards

153.3°C/W

128.5°C/W

115.5°C/W

Multi-Layer PCB, JEDEC Standard Test Boards

112.7°C/W

103.3°C/W

97.1°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

TRANSISTOR COUNT

The transistor count for ICS840-77 is: 2423



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PACKAGE OUTLINE - G SUFFIX FOR 8 LEAD TSSOP

PACKAGE OUTLINE - M SUFFIX FOR 8 LEAD SOIC

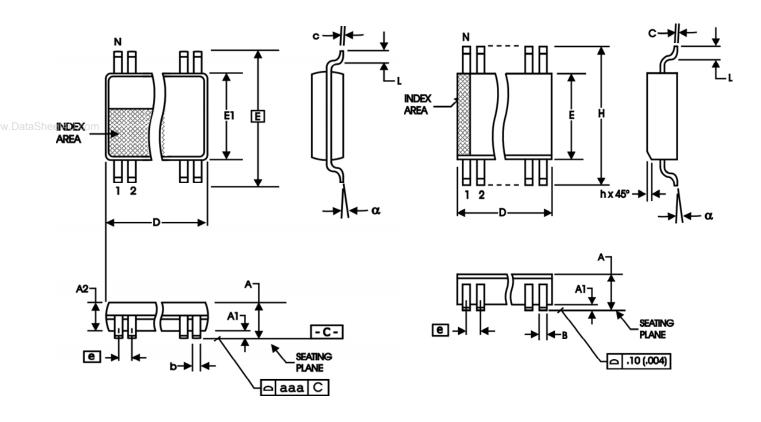


TABLE 8A. PACKAGE DIMENSIONS

SYMBOL	Millin	neters	
STWBOL	Minimum	Maximum	
N	8	3	
А		1.20	
A1	0.05	0.15	
A2	0.80	1.05	
b	0.19	0.30	
С	0.09	0.20	
D	2.90	3.10	
E	6.40 BASIC		
E1	4.30	4.50	
е	0.65 BASIC		
L	0.45	0.75	
α	0°	8°	
aaa		0.10	

Reference Document: JEDEC Publication 95, MO-153

TABLE 8B. PACKAGE DIMENSIONS

SYMBOL	Millimeters				
STWBOL	MINIMUM	MAXIMUM			
N		8			
А	1.35	1.75			
A1	0.10	0.25			
В	0.33	0.51			
С	0.19	0.25			
D	4.80	5.00			
E	3.80	4.00			
е	1.27	BASIC			
Н	5.80	6.20			
h	0.25	0.50			
L	0.40	1.27			
α	0°	8°			

Reference Document: JEDEC Publication 95, MS-012



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TABLE 9. ORDERING INFORMATION

	Part/Order Number	Marking	Package	Shipping Packaging	Temperature
	ICS840AG-77	40A77	8 lead TSSOP	tube	0°C to 70°C
	ICS840AG-77T	40A77	8 lead TSSOP	2500 tape & reel	0°C to 70°C
	ICS840AG-77LF	TBD	8 lead "Lead-Free" TSSOP	tube	0°C to 70°C
	ICS840AG-77LFT	TBD	8 lead "Lead-Free" TSSOP	2500 tape & reel	0°C to 70°C
	ICS840AM-77	TBD	8 lead SOIC	tube	0°C to 70°C
e	t4U ICS840AM-77T	TBD	8 lead SOIC	2500 tape & reel	0°C to 70°C
	ICS840AM-77LF	TBD	8 lead "Lead-Free" SOIC	tube	0°C to 70°C
	ICS840AM-77LFT	TBD	8 lead "Lead-Free" SOIC	2500 tape & reel	0°C to 70°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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